





General Multilayer Ceramic Capacitors



MLCC is an electronic part that temporarily stores an electrical charge and the most prevalent type of capacitor today. New technologies have enabled the MLCC manufacturers to follow the trend dictated by smaller and smaller electronic devices such as Cellular telephones, Computers, DSC, DVC

General Features

- Miniature Size
- Wide Capacitance and Voltage Range
- Tape & Reel for Surface Mount Assembly
- Low ESR

Applications

- General Electronic Circuit

Part Numbering

CL	<u>10</u>	<u>B</u>	<u>104</u>	K	<u>B</u>	<u>8</u>	N	N	N	<u>C</u>
Ű	2	6	4	6	6	U	8	9	10	(

- Samsung Multilayer Ceramic Capacitor
- 2 Size(mm)
- 3 Capacitance Temperature Characteristic
- 4 Nominal Capacitance
- **5** Capacitance Tolerance
- 6 Rated Voltage

- Thickness Option
- 8 Product & Plating Method
- Samsung Control Code
- Reserved For Future Use
- Packaging Type

1 Samsung Multilayer Ceramic Capacitor

2 SIZE(mm)

Code	EIA CODE	Size(mm)
03	0201	0.6 × 0.3
05	0402	1.0 × 0.5
10	0603	1.6 × 0.8
21	0805	2.0 × 1.25
31	1206	3.2 × 1.6
32	1210	3.2 × 2.5
43	1812	4.5 × 3.2
55	2220	5.7 × 5.0





3 CAPACITANCE TEMPERATURE CHARACTERISTIC

Code		Temperature Characteristics				
С		COG	C△	0 ± 30 (ppm/ °C)		
P		P2H	P△	-150 ± 60		
R		R2H	R△	-220±60		
S	Class	S2H	S△	-330±60	-55 ~ +125℃	
Т		T2H	T△	-470±60		
U		U2J	U△	-750 ± 60		
L		S2L	S△	+350 ~ -1000		
Α		X5R	X5R	±15%	-55 ~ +85℃	
В	Class II	X7R	X7R	±15%	-55 ~ +125℃	
Х	Ciass II	X6S	X6S	±22%	-55 ~ +105℃	
F		Y5V	Y5V	+22 ~ -82%	-30 ~ +85℃	

***** Temperature Characteristic

Temperature Characteristics	Below 2.0pF	2.2 ~ 3.9pF	Above 4.0pF	Above 10pF
С∆	C0G	C0G	C0G	C0G
РΔ	-	P2J	P2H	P2H
R∆	-	R2J	R2H	R2H
SΔ	-	S2J	S2H	S2H
т∆	-	T2J	T2H	T2H
UΔ	-	U2J	U2J	U2J

 $J:\pm 120 PPM/{}^{\circlearrowright},\, H:\pm 60 PPM/{}^{\circlearrowleft},\, G:\pm 30 PPM/{}^{\circlearrowleft}$

4 NOMINAL CAPACITANCE

Nominal capacitance is identified by 3 digits.

The first and second digits identify the first and second significant figures of the capacitance.

The third digit identifies the multiplier. 'R' identifies a decimal point.

Example

Code	Nominal Capacitance
1R5	1.5pF
103	10,000pF, 10nF, 0.01 µ F
104	100,000pF, 100nF, 0.1 µ F





O CAPACITANCE TOLERANCE

Code	Tolerance	Nominal Capacitance
Α	±0.05pF	
В	±0.1pF	
С	±0.25pF	Less than 10pF (Including 10pF)
D	± 0.5pF	(modaling Topi)
F	±1pF	
F	±1%	
G	±2%	
J	±5%	Mara than 10pF
K	±10%	More than 10pF
М	±20%	
Z	+80, -20%	

6 RATED VOLTAGE

Code	Rated Voltage	Code	Rated Voltage
R	4.0V	D	200V
Q	6.3V	E	250V
Р	10V	G	500V
О	16V	Н	630V
Α	25V	I	1,000V
L	35V	J	2,000V
В	50V	К	3,000V
С	100 V		





THICKNESS OPTION

Size	Code	Thickness(T)	Size	Code	Thickness(T)
0201(0603)	3	0.30±0.03		F	1.25±0.20
0402(1005)	5	0.50±0.05		н	1.6±0.20
0603(1608)	8	0.80±0.10	1812(4532)	I	2.0±0.20
	Α	0.65±0.10		J	2.5±0.20
	С	0.85±0.10		L	3.2±0.30
0805(2012)	F	1.25±0.10		F	1.25±0.20
	Q	1.25±0.15		н	1.6±0.20
	Y	1.25±0.20	2220(5750)	I	2.0±0.20
	С	0.85±0.15		J	2.5±0.20
1206(3216)	F	1.25±0.15		L	3.2±0.30
	Н	1.6±0.20			
	F	1.25±0.20			
	Н	1.6±0.20			
1210(3225)	ı	2.0±0.20			
	J	2.5±0.20			
	V	2.5±0.30			

PRODUCT & PLATING METHOD

Code	Electrode	Termination	Plating Type
Α	Pd	Ag	Sn_100%
N	Ni	Cu	Sn_100%
G	Cu	Cu	Sn_100%

SAMSUNG CONTROL CODE

Code	Description of the code	Code	Description of the code
Α	Array (2-element)	N	Normal
В	Array (4-element)	Р	Automotive
С	High - Q	L	LICC





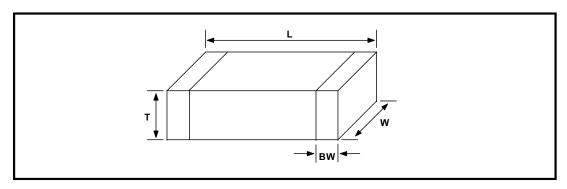
• RESERVED FOR FUTURE USE

Code	Description of the code
N	Reserved for future use

1 PACKAGING TYPE

Code	Packaging Type	Code	Packaging Type
В	Bulk	F	Embossing 13" (10,000EA)
Р	Bulk Case	L	Paper 13" (15,000EA)
С	Paper 7"	0	Paper 10"
D	Paper 13" (10,000EA)	S	Embossing 10"
Е	Embossing 7"		

APPEARANCE AND DIMENSION



CODE	EIA CODE		DIMENSION (mm)								
CODE	LIX GODE	L	w	T (MAX)	BW						
03	0201	0.6 ± 0.03	0.3 ± 0.03	0.33	0.15 ± 0.05						
05	0402	1.0 ± 0.05	0.5 ± 0.05	0.55	0.2 +0.15/-0.1						
10	0603	1.6 ± 0.1	0.8 ± 0.1	0.9	0.3 ± 0.2						
21	0805	2.0 ± 0.1	1.25 ± 0.1	1.35	0.5 +0.2/-0.3						
24	4000	3.2 ± 0.15	1.6 ± 0.15	1.40	0.5 +0.2/-0.3						
31	1206	3.2 ± 0.2	1.6 ± 0.2	1.8	0.5 +0.3/-0.3						
20	1010	3.2 ± 0.3	2.5 ± 0.2	2.7	0.6 + 0.2						
32	1210	3.2 ± 0.4	2.5 ± 0.3	2.8	0.6 ± 0.3						
43	1812	4.5 ± 0.4	3.2 ± 0.3	3.5	0.8 ± 0.3						
55	2220	5.7 ± 0.4	5.0 ± 0.4	3.5	1.0 ± 0.3						





NO	ITE	М	PER	FORMANCE	TEST	CONDITION			
1	Appea	rance	No Abnormal Exterior	Appearance	Through Microscope(×10)			
2	Insula Resist		10,000MΩ or 500MΩ·μF Rated Voltage is below 10,000MΩ or 100MΩ·μF	w 16V ;	Apply the Rated Voltage For 60 ~ 120 Sec.				
3	Withsta	Ü	No Dielectric Breakdown		Class I : 300% of the Rated Voltage for 1~5 sec. Class II :250% of the Rated Voltage for 1~5 sec. is applied with less than $50\text{m}\text{A}$ current				
					Capacitance	Frequency	Voltage		
		Class I	Within the specifie	ed tolerance	≤ 1,000 pF	1Mb ±10%			
	Capacita	1			>1,000 pF	1 kHz ±1 0%	0.5 ~ 5 Vrms		
4	nce				Capacitance	Frequency	Voltage		
		Class	Within the specif	ied tolerance	≤ 10 µF	1 kHz ±1 0%	1.0±0.2Vrms		
		П			>10 µF	120 Hz ± 20 %	0.5±0.1Vrms		
			Capacitance ≥ 30pF	: Q ≥ 1,000	Capacitance	Frequency	Voltage		
5	Q	Class	< 30pF	: Q ≥ 400 +20C	≤ 1,000 pF	1M½ ±10%			
		I	(0	C : Capacitance)	>1,000 pF	1 kHz ±1 0%	0.5 ~ 5 Vrms		
			1. Characteristic : A(X5R), B(X7R), X(X6S)	Capacitance	Frequency	Voltage		
			Rated Voltage	Spec	≤ 10 <i>μ</i> F	1kHz ±10%	1.0±0.2Vrms		
			≥ 25V	0.025 max	>10 <i>μ</i> F	120 Hz ± 20 %	0.5±0.1Vrms		
			16V	0.035 max					
			10V	0.05 max	1				
			6.3V	0.05 max/ 0.10max*1	*1. 0201 C≥0.022uF, 0	•			
			2. Characteristic : F(Y5V)	1812 C≥47uF, 2220	0805 C≥4.7uF, 1206 C≥10uF, 1210 C≥22uF, 1812 C≥47uF, 2220 C≥100uF, All Low Profile Capacitors (P.16).			
6	Tan∂	Class	Rated Voltage	Spec	*3. 0402 C≥0.033uF, 06				
		П	50V	0.05 max, 0.07max*2	All 0805, 1206 size		F		
			35V 25V	0.07 max 0.05 max/ 0.07 max* ³ / 0.09max* ⁴	*4 1210 C>6.8uF *5 0402 C≥0.22uF	. 1210 C>6.8uF			
		16V		0.09 max/ 0.125max*5	*6 All 1812 size				
	10V		0.125 max/ 0.16max*6						
	6.3V			0.16max					





NO	ITE	M		PERFOR	RMANCE		TEST CONDITION			
	.,,,,					Canacitance s	shall be measured by the steps			
				- 1			following table.			
			Characte	ristics	Temp. Coefficient (PPM°C)	Step	Temp.(℃)			
			COC	, +	0 ± 30	l	25 ± 2			
			PH	—— <u> </u>	-150 ± 60	1				
		Class	RH		-220 ± 60	2	Min. operating temp. ± 2			
		I	SH	-	-330 ± 60	3	25 ± 2			
			TH	-	-470 ± 60	4	Max. operating temp ± 2			
				UL		-750 ± 120	5	25 ± 2		
			SL		+350 ~ -1000	(1) Class I				
	_					· '	Coefficient shall be calculated from			
_	Temperature					the formula as				
7	Characteristics of Capacitance					Temp, Coefficient = $\frac{\text{C2 - C1}}{\text{C1} \times \triangle \text{T}} \times 10^6 \text{ [ppr]}$				
						C1; Capacita	ince at step 3			
			Ch - · · ·	wistis -	Capacitance Change	C2: Capacita				
			Characte	eristics	with No Bias	△T: 60°C(=8	5℃-25℃)			
		Class II	A(X5 B(X7	R)/ 'R)	± 15%	(2) CLASS II				
			X(X6	SS)	± 22%	Capacitance (Change shall be calculated from the			
			F(Y5	-	+22% ~ -82%	formula as below.				
			` ` ` `	,		△C = <u>C2 -</u>	<u>C1</u> × 100(%)			
							ince at step 3			
							ince at step 2 or 4			
							* Pressure for 10±1 sec.			
							201 case size.			
8	Adhesive	Strength	No Indicati	on Of Pee	eling Shall Occur On The	500g.f				
	of Termi	ination	Terminal E	lectrode.						
						Bending limit	; 1mm			
		Apperance	No mecha	nical dan	nage shall occur.	Test speed ;	1.0mm/SEC.			
			Charact	tarietics	Capacitance Change	Keep the test	board at the limit point in 5 sec.,			
			Citataci	CHOUCS	Capacitance Change	Then measure	e capacitance.			
					Within \pm 5% or \pm 0.					
			Clas	ss I	5 pF whichever is		.20			
	D din .				larger		R=230			
9	Bending Strength			A(X5R)/		50	<u>/_</u> /			
	Strength	Capacitance		B(X7R)/		<u> </u>	▲			
				X(X6S)						
				7.(7.00)		—	Bending limit			
			Class II			45±1	45±1			
				F(Y5V)	Within ±30%					





NO	17	EM		PERFORMANCE TEST CONDITION						
					ne terminal surface is to	Solder	Sn-3Ag-0.5	Cu 63Sn-37Pb		
				d newly, So or dissolve	o metal part does not	Solder	245±5℃ 235±5℃			
10	Solde	erability				Temp.	·			
			 /	//	/ //	Dip Time				
						Pre-heatin	Pre-heating at 80~120℃ for 10~30 sec.			
		Apperance	No mecha	anical dam	age shall occur.		nperature: 270	±5℃		
			Charac	teristics	Capacitance Change	·	10±1 sec.	fully immersed and		
			Clas	_ T	Within ±2.5% or		as below:	idily illillersed and		
			Clas	S 1	±0.25 pF whichever is larger					
		Capacitance		A(X5R)/	M/#h:= 17 F0/	STEP	TEMP.(℃)	TIME(SEC.)		
				B(X7R)	Within ±7.5%	1	80~100	60		
			Class II	X(X6S)	Within ±15%	2	150~180	60		
11	Resistance to			F	Within ±20%		•	bient condition for		
	Soldering heat	Q	Capacitan	ice ≥ 30pF	: Q≥ 1000	specified time* before measurement * 24 ± 2 hours (Class I)				
	_	(Class I)		<30 pF	: Q≥ 400+20×C (C: Capacitance)		nours (Class I			
		Tan δ								
		(Class Ⅱ)	Within the	specified	initial value					
		Insulation Resistance	Within the	specified	initial value					
		Withstanding Voltage	Within the	specified	initial value					
		Appearance	No mecha	anical dam	age shall occur.					
			Charact	eristics	Capacitance Change					
			Olean	_ T	Within ±2.5% or		itor shall be su Motion having a	bjected to a a total amplitude of		
			Clas	S 1	±0.25pF whichever is larger		•	y from 10Hz to 55H		
	Vibration	Capacitance	Class	A(X5R)/ B(X7R)	Within ±5%		to 10Hz In 1 m			
12	Test		П	X(X6S)	Within ±10%		s for 2hours ea lar directions	ch in 3 mutually		
				F(Y5V)	Within ±20%	Porporidion	.c. directions			
		Q (Class I)	Within the	specified	initial value					
		Tan δ (Class ${\mathbb I}$)	Within the	specified	initial value					
		Insulation Resistance	Within the	e specified	initial value					





NO	ITE	M		PERFO	RMANCE	TEST CONDITION
		Appearance	No mechanic	cal damage shal		Temperature : 40±2 ℃
			Chara	cteristics	Capacitance Change	Relative humidity : 90~95 %RH
			Cla	ss I	Within ±5.0% or ±0.5pF whichever is larger	Duration time : 500 +12/-0 hr.
		Capacitance	Class	A(X5R)/ B(X7R)/ X(X6S)	Within ±12.5%	Leave the capacitor in ambient condition for specified time* before measurement.
				F(Y5V)	Within ±30%	CLASSI : 24±2 Hr CLASSII : 24±2 Hr.
13	Humidity (Steady	Q CLASS I	10≤ Capacit	-	350 1≥ 275 + 2.5×C 200 + 10×C (C: Capacitance)	- OLASSII . 2422 III.
	State)		1. Characteristic: A(X5R), B(X7R) 0.05max (16V and over)		Characteristic : F(Y5V) 0.075max (25V and over)	
		Tan ∂ CLASS II	0.075max (10 0.075max	OV)	0.1max (16V, C<1.0μF) 0.125max(16V, C≥1.0μF)	
			(6.3V excep 0.125max* (refer to Tab		0.15max (10V) 0.195max (6.3V)	
		Insulation Resistance	1,000 MΩ or	50MΩ·μF whichev	ver is smaller.	
		Appearance	No mechanic	cal damage shal	Applied Voltage : rated voltage	
				ss I	Capacitance Change Within ±5.0% or ±0.5pF whichever is larger	Temperature : 40±2 °C Humidity : :90~95%RH Duration Time : 500 +12/-0 Hr. Charge/Discharge Current : 50mA max.
		Capacitance		A(X5R)/ B(X7R)/ X(X6S)	Within ±12.5% Within ±12.5% Within ±30%	Perform the initial measurement according to Note1.
			Class II	F(Y5V)	Within ±30%	Perform the final measurement according to Note2.
14	Moisture Resistance	Q (Class I)		≥ 30 pF : Q≥ 2 <30 pF : Q≥ 10	00 00 + 10/3×C (C: Capacitance)	
		Tan ∂ (Class Ⅱ)	0.05max (16\) 0.075max (10\) 0.075max (6.3V excep 0.125max* (refer to Tal	ot Table 1)	2. Characteristic : F(Y5V) 0.075max (25V and over) 0.1max (16V, C<1.0μF) 0.125max(16V, C≥ 1.0μF) 0.15max (10V) 0.195max (6.3V)	
		Insulation Resistance	500 MΩ or 25	5MΩ·μF whichever	r is smaller.	





NO	ITEI	М		PER	FORMANCE		TEST CONDIT	ION	
		Appearance	No mechanio	cal damage	shall occur.	1 '''	oltage: 200%* of the	-	
			Charact	eristics	Capacitance Change		ime: 1000 +48/-0 H		
			Class	. т	Within ±3% or ±0.3pF,	Charge/Discharge Current : 50mA max.			
			Class I		Whichever is larger	* refer to	table(3): 150%/100	% of the rated	
		Capacitance		A(X5R)/ B(X7R)	Within ±12.5%	voltage	· ,		
			Class II	X(X6S)	Within ±25%	Perform th	e initial measurement	according to	
				F(Y5V)	Within ±30%	Note1 for	Class II		
				1(101)	Within ±30%				
		Q (Class I)		tance <30 p	Q ≥ 350 F : Q ≥ 275 + 2.5×C ≥ 200 +10×C (C: Capacitance)	Perform th Note2.	e final measurement	according to	
	High		Characteri			-			
15	Temperature Resistance	Tan δ (Class ${\rm II}$) Insulation Resistance	0.05max (16V and o 0.075max (10 0.075max (6.3V excep 0.125max* (refer to Tall X(X6S) 0.11n	ot Table 1) ble 1) max (6.3V a	0.075max (25V and over) 0.1max(16V, C<1.0μ□) 0.125max(16V, C≥1.0μ□) 0.15max (10V) 0.195max (6.3V)				
		Appearance	No mechanio	cal damage	shall occur.		shall be subjected	d to 5 cycles.	
			Charact	eristics	Capacitance Change		for 1 cycle :	Timo(min.)	
		Capacitance	Class	A(X5R)	Within ±2.5% or ±0.25 pF Whichever is larger	Step - 1	Temp.($^{\circ}$) Min. operating temp.+0/-3	Time(min.)	
		Sapadilaride	Class	B(X7R)/	Within ±7.5%	2	25	2~3	
16	Temperature Cycle		П	X(X6S) F(Y5V)	Within ±15% Within ±20%	3	Max. operating temp.+3/-0	30	
		Q			<u> </u>	4	25	2~3	
		(Class I)	Within the sp	pecified initia	al value	Leave the	e capacitor in amb	ient condition	
		Tan δ (Class Π)	Within the sp	pecified initia	al value	* 24 ± 2	ied time* before m hours (Class I)	neasurement	
		Insulation Resistance	Within the sp	pecified initia	al value	24 ± 2 hours (Class II)			





		Reco	ommended Sold	ering Method		
		Size	Temperature		Cond	lition
		inch (mm)	Characteristic	Capacitance	Flow	Reflow
		0201 (0603)	-	-	-	0
		0402 (1005)				
		0603 (1608)	Class I	-	0	0
			Class II	$C < 1\mu F$	0	0
			Class II	C ≥ 1 µF	-	0
	Recommended		Class I	-	0	0
18	Soldering Method	0805 (2012)	Class II	C < 4.7μF	0	0
	By Size & Capacitance		Class II	C ≥ 4.7 <i>μ</i> F	-	0
	by the a capation		Array	-	-	0
			Class I	-	0	0
		1206 (3216)	Class II	C < 10μF	0	0
		1200 (3210)	Class II	C ≥ 10 μF	-	0
			Array	-	-	0
		1210 (3225)				0
		1808 (4520)				0
		1812 (4532)	-	-	-	0
		2220 (5750)				0

Note1. Initial Measurement For Class ${\rm I\hspace{-.1em}I}$

Perform the heat treatment at 150 $^{\circ}$ C+0/-10 $^{\circ}$ for 1 hour. Then Leave the capacitor in ambient condition for 48±4 hours before measurement. Then perform the measurement.

Note2. Latter Measurement

1. CLASS I

Leave the capacitor in ambient condition for 24±2 hours before measurement

Then perform the measurement.

2. Class ${\mathbb I}$

Perform the heat treatment at $150\,\text{°C} + 0\text{l} + 10\,\text{°C}$ for 1 hour. Then Leave the capacitor in ambient condition for 48 ± 4 hours before measurement. Then perform the measurement.

*Table1.

Tan δ 0.125max* $0201 C \ge 0.022 \mu F$ $0402 C \ge 0.22 \mu F$ $0603 C \ge 2.2 \mu F$ $0805 C \ge 4.7 \mu F$ $1206 C \ge 10.0 \mu F$ $1210 C \ge 22.0 \mu F$ $1812 C \ge 47.0 \mu F$ $2220 C \ge 100.0 \mu F$ All Low Profile Capacitors (P.16).

*Table2.

High Temperature Resistance test								
⊿C (Y5V)	± 30%							
	0402 C ≥ 0.47 μF							
	0603 C ≥ 2.2μF							
Class ∏	0805 C ≥ 4.7μ F							
0.0001	1206 C ≥ 10.0 μF							
F(Y5V)	1210 C ≥ 22.0 <i>μ</i> F							
	1812 C ≥ 47.0 <i>μ</i> F							
	2220 C ≥ 100.0 <i>μ</i> F							

*Table3.

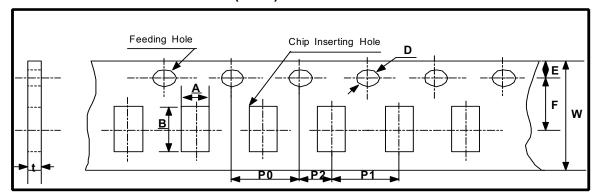
	High Temperature Resistance test											
Applied Voltage	100% of the rated voltage	150% of the rated voltage										
Class II A(X5R), B(X7R), X(X6S), F(Y5V)	0201 C \geq 0.1 μF 0402 C \geq 1.0 μF 0603 C \geq 4.7 μF 0805 C \geq 22.0 μF 1206 C \geq 47.0 μF 1210 C \geq 100.0 μF All Low Profile Capacitors (P.16).	$\begin{array}{cccccccccccccccccccccccccccccccccccc$										





PACKAGING

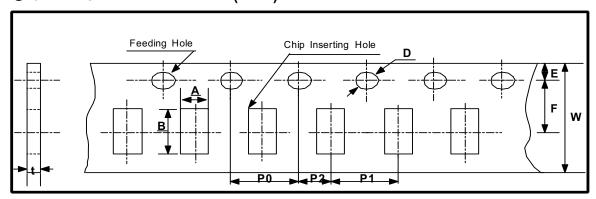
● CARDBOARD PAPER TAPE (4mm)



unit: mm

_	mbol ype	Α	В	w	F	E	P1	P2	P0	D	t
D i m	0603 (1608)	1.1 ±0.2	1.9 ±0.2								
e n s	0805 (2012)	1.6 ±0.2	2.4 ±0.2	8.0 ±0.3	3.5 ±0.05	1.75 ±0.1	4.0 ±0.1	2.0 ±0.05	4.0 ±0.1	Ф1.5 +0.1/-0	1.1 Below
i o n	1206 (3216)	2.0 ±0.2	3.6 ±0.2								

● CARDBOARD PAPER TAPE (2mm)



unit: mm

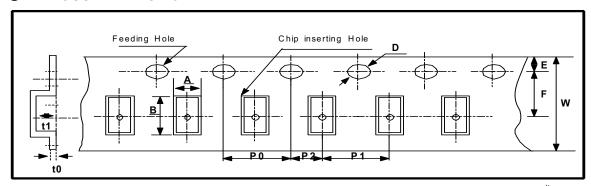
Symbol Type		Α	В	w	F	E	P1	P2	P0	D	t
D i m e n s i o n	0201 (0603)	0.38 ±0.03	0.68 ±0.03	8.0	3.5	1.75	2.0	2.0 ±0.05	4.0 ±0.1	Ф1.5 +0.1/-0.03	0.37 ±0.03
	0402 (1005)	0.62 ±0.04	1.12 ±0.04	±0.3	±0.05	±0.1	±0.05				0.6 ±0.05





PACKAGING

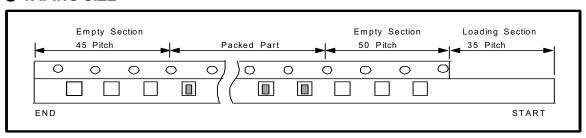
● EMBOSSED PLASTIC TAPE



 $u\,n\,it\,:\,m\,m$

	m bol ype	Α	В	w	F	E	P1	P 2	P 0	D	t1	t0
	0805 (2012)	1.45 ±0.2	2.3 ±0.2									
D	1206 (3216)	1.9 ±0.2	3.5 ±0.2	8.0 ±0.3	3.5 ±0.05		4.0 ±0.1				2.5 max	
m e	1210 (3225)	2.9 ±0.2	3.7 ±0.2			1.75		2.0	4.0	Ф1.5 +0.1/-0		0.6
n s i	1808 (4520)	2.3 ±0.2	4.9 ±0.2			±0.1		±0.05	±0.1	+0.17-0		Below
o n	1812 (4532)	3.6 ±0.2	4.9 ±0.2	12.0 ±0.3	5.60 ±0.05		8.0 ±0.1				3.8 max	
	2220 (5750)	5.5 ±0.2	6.2 ±0.2									

TAPING SIZE



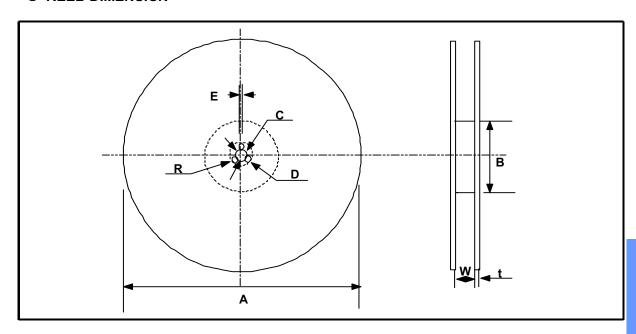
Type	Symbol	Size	Cardboard Paper Tape	Symbol	Size	Embossed Plastic Tape
		0201(0603)	10,000		All Size ≤ 3216 1210(3225),1808(4520) (t≤ 1.6mm)	2,000
7" Reel	С	0402(1005)	10,000	E	1210(3225)(t≥2.0 m m)	1,000
		OTHERS	4,000		1808(4520)(t≥2.0mm)	1,000
10" Reel	0	-	10,000	-	-	-
	D	0402(1005)	50,000		All Size ≤ 3216 1210(3225),1808(4520) (t<1.6mm)	10,000
		OTHERS	10,000		$1210(3225)(1.6 \le t < 2.0 \text{mm})$ $1206(3216)(1.6 \le t)$	8,000
13" Reel		0603(1608)	10,000 or 15,000	F	$1210(3225),1808(4520)$ $(t \ge 2.0 \text{mm})$	4,000
	L	L 0805(2012) 15,000 or (t≤0.85mm) 10,000(Option)		1812(4532)(t≤2.0 m m)	4,000	
	(1206(3216) 1206(3216) (t≤0.85mm) 10,000			1812(4532)(t>2.0mm) 5750(2220)	2,000	





PACKAGING

• REEL DIMENSION



unit : mm

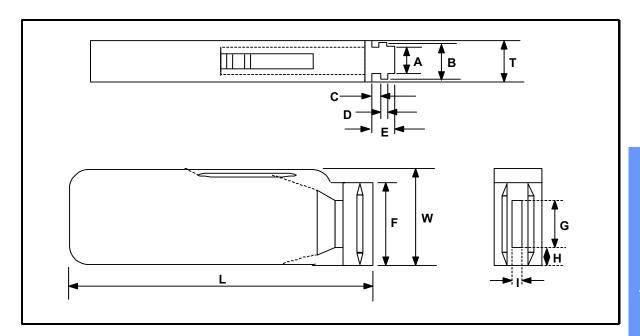
Symbol	Α	В	С	D	E	W	t	R
7" Reel	ф180+0/ -3	ф60+1/ -3	140 100	0.100	00105	0.14.5	1.2±0.2	4.0
13" Reel	ф330±2.0	ф80+1/ -3	φ13±0.3 25±0.5	∠.0±0.5	9±1.5	2.2±0.2	1.0	





BULK CASE PACKAGING

- Bulk case packaging can reduce the stock space and transportation costs.
- The bulk feeding system can increase the productivity.
- It can eliminate the components loss.



unit: mm

Symbol	Α	В	Т	С	D	E
Dimension	6.8±0.1	8.8±0.1	12±0.1	1.5+0.1/-0	2+0/-0.1	3.0+0.2/-0

Symbol	F	W	G	Н	L	I
Dimension	31.5+0.2/-0	36+0/-0.2	19±0.35	7 ± 0.35	110±0.7	5±0.35

QUANTITY OF BULK CASE PACKAGING

unit : pcs

0:	0402/4005)	0602/4600)	0805(2012)		
Size	0402(1005)	0603(1608)	T=0.65mm	T=0.85mm	
Quantity	50,000	10,000 or 15,000	10,000	5,000 or 10,000	

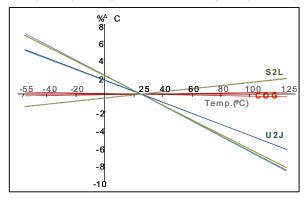


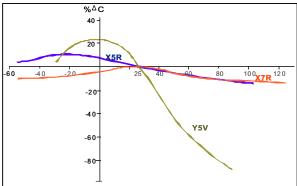


APPLICATION MANUAL

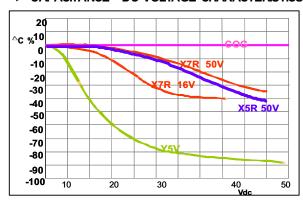
• ELECTRICAL CHARACTERISTICS

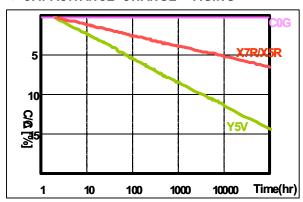
► CAPACITANCE - TEMPERATURE CHARACTERISTICS



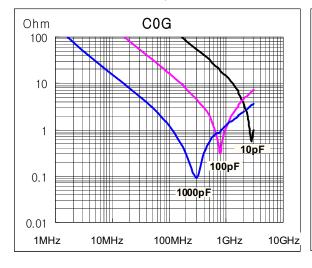


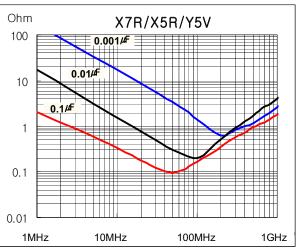
► CAPACITANCE - DC VOLTAGE CHARACTERISTICS ► CAPACITANCE CHANGE - AGING





► IMPEDANCE - FREQUENCY CHARACTERISTICS









STORAGE CONDITION

▶ Storage Environment

The electrical characteristics of MLCCs were degraded by the environment of high temperature or humidity. Therefore, the MLCCs shall be stored in the ambient temperature and the relative humidity of less than 40°C and 70%, respectively.

Guaranteed storage period is within 6 months from the outgoing date of delivery.

Corrosive Gases

Since the solderability of the end termination in MLCC was degraded by a chemical atmosphere such as chlorine, acid or sulfide gases, MLCCs must be avoid from these gases.

▶ Temperature Fluctuations

Since dew condensation may occur by the differences in temperature when the MLCCs are taken out of storage, it is important to maintain the temperature-controlled environment.

DESIGN OF LAND PATTERN

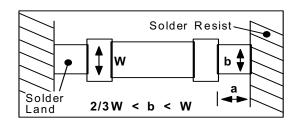
When designing printed circuit boards, the shape and size of the lands must allow for the proper amount of solder on the capacitor.

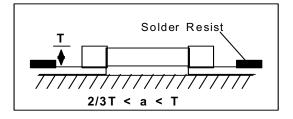
The amount of solder at the end terminations has a direct effect on the crack.

The crack in MLCC will be easily occurred by the tensile stress which was due to too much amount of solder. In contrast, if too little solder is applied, the termination strength will be insufficiently.

Use the following illustrations as guidelines for proper land design.

Recommendation of Land Shape and Size.









ADHESIVES

When flow soldering the MLCCs, apply the adhesive in accordance with the following conditions.

Requirements for Adhesives

They must have enough adhesion, so that, the chips will not fall off or move during the handling of the circuit board.

They must maintain their adhesive strength when exposed to soldering temperature.

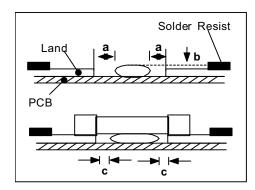
They should not spread or run when applied to the circuit board.

They should harden quickly. They should not corrode the circuit board or chip material.

They should be a good insulator. They should be non-toxic, and not produce harmful gases, nor be harmful when touched.

Application Method

It is important to use the proper amount of adhesive. Too little and much adhesive will cause poor adhesion and overflow into the land, respectively.



		unit : mm
Туре	21	31
а	0.2 min	0.2 min
b	70~100 ^{µm}	70~100 ^{µm}
С	> 0	> 0

▶ Adhesive hardening Characteristics

To prevent oxidation of the terminations, the adhesive must harden at 160 °C or less, within 2 minutes or less.

MOUNTING

▶ Mounting Head Pressure

Excessive pressure will cause crack to MLCCs. The pressure of nozzle will be 300g maximum during mounting.

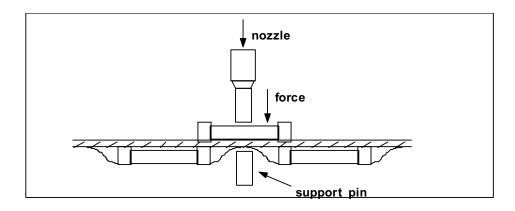




▶ Bending Stress

When double-sided circuit boards are used, MLCCs first are mounted and soldered onto one side of the board. When the MLCCs are mounted onto the other side,

it is important to support the board as shown in the illustration. If the circuit board is not supported, the crack occur to the ready-installed MLCCs by the bending stress.



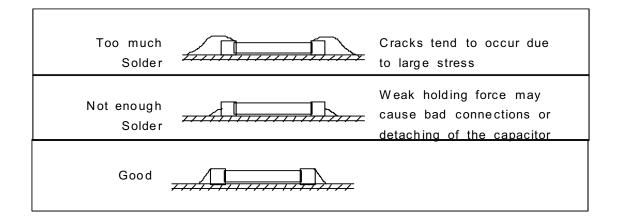
▶ Manual Soldering

Manual soldering can pose a great risk of creating thermal cracks in chip capacitors.

The hot soldering iron tip comes into direct contact with the end terminations, and operator's carelessness may cause the tip of the soldering iron to come into direct contact with the ceramic body of the capacitor.

Therefore the soldering iron must be handled carefully, and close attention must be paid to the selection of the soldering iron tip and to temperature control of the tip.

► Amount of Solder







▶ Cooling

Natural cooling using air is recommended. If the chips are dipped into solvent for cleaning, the temperature difference($\triangle T$) must be less than 100 $^{\circ}$ C

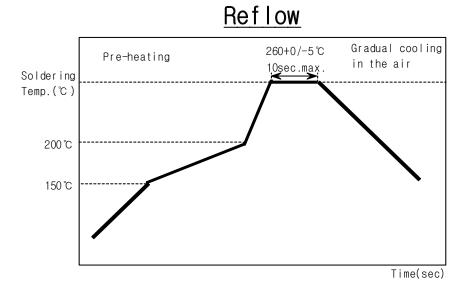
▶ Cleaning

If rosin flux is used, cleaning usually is unnecessary. When strongly activated flux is used, chlorine in the flux may dissolve into some types of cleaning fluids, thereby affecting the chip capacitors. This means that the cleaning fluid must be carefully selected, and should always be new.

▶ Notes for Separating Multiple, Shared PC Boards.

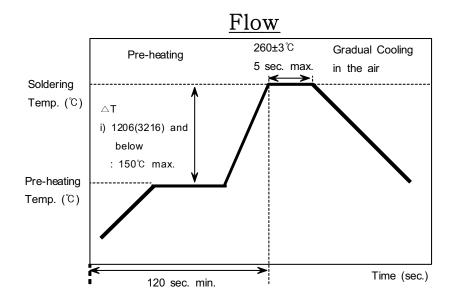
A multi-PC board is separated into many individual circuit boards after soldering has been completed. If the board is bent or distorted at the time of separation, cracks may occur in the chip capacitors. Carefully choose a separation method that minimizes the bending often circuit board.

▶ Recommended Soldering Profile









Soldering Iron

Variation of Temp.	Soldering	Pre-heating	Soldering	Cooling
	Temp (℃)	Time (Sec)	Time(Sec)	Time(Sec)
△T≤130	300±10℃max	≥ 60	≤ 4	-

	facilities	
Wattage	Tip Diameter	Soldering Time
20W Max	3mm Max	4 Sec Max

* Caution - Iron Tip Should Not Contact With Ceramic Body Directly.